NSN 5962-01-332-0722

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-332-0722 **Overall Width:** 0.720 inches **Body Length:** Between 0.595 inches and 0.630 inches **Body Width:** Between 0.404 inches and 0.420 inches **Body Height:** Between 0.060 inches and 0.090 inches **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and burn in and programmable and 3-state output and electrostatic sensitive **Inclosure Material:** Ceramic **Inclosure Configuration:** Flat pack **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 14 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 5.5 volts power source **Time Rating Per Chacteristic:** 50.00 nanoseconds propagation delay time, low to high level output and 50.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Rom **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 24 flat leads Shelf Life: N/a **Unit Of Measure:**

Fiig:

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Demilitarization: Yes - demil/mli